NSN 5962-01-127-2146

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View Online at https://aerobasegroup.com/nsn/5962-01-127-2146

Body Length: 0.910 inches **Body Width:** Between 0.290 inches and 0.310 inches **Body Height:** 0.165 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+85.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Po ok-398 fscm 05869 **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/enable **Inclosure Material:** Ceramic and glass Inclosure Configuration: Dual-in-line **Output Logic Form:** P-type metal oxide-semiconductor logic **Input Circuit Pattern:** 13 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 20.0 volts power source

Time Rating Per Chacteristic:

40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Test Data Document:

05869-725000 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

18 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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